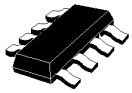
74V2T04

TRIPLE INVERTER

- HIGH SPEED: t_{PD} = 4.7ns (TYP.) at V_{CC} = 5V
- LOW POWER DISSIPATION: I_{CC} = 1µA(MAX.) at T_A = 25°C
- COMPATIBLE WITH TTL OUTPUTS: V_{IH} = 2V (MIN), V_{IL} = 0.8V (MAX)
- POWER DOWN PROTECTION ON INPUT
- SYMMETRICAL OUTPUT IMPEDANCE: $|I_{OH}| = I_{OL}$ = 8mA (MIN) at V_{CC} = 4.5V
- BALANCED PROPAGATION DELAYS: $t_{PLH} \cong t_{PHL}$
- OPERATING VOLTAGE RANGE: V_{CC}(OPR) = 4.5V to 5.5V
- IMPROVED LATCH-UP IMMUNITY



SOT23-8L

ORDER CODES

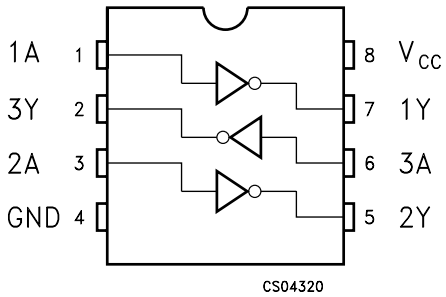
PACKAGE	T & R
SOT23-8L	74V2T04STR

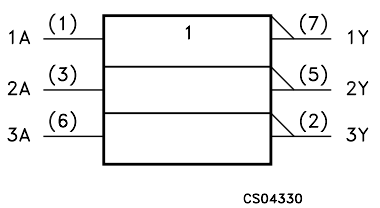
DESCRIPTION

The 74V2T04 is an advanced high-speed CMOS TRIPLE INVERTER fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology.

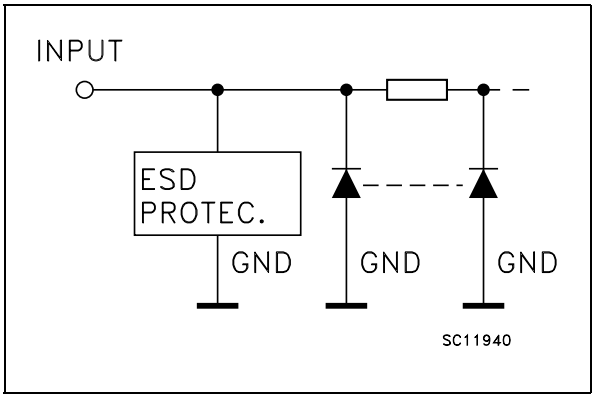
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.
Power down protection is provided on input and 0 to 7V can be accepted on input with no regard to the supply voltage. This device can be used to interface 5V to 3V.

PIN CONNECTION AND IEC LOGIC SYMBOLS





INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN N°	SYMBOL	NAME QND FUNCTION
1, 3, 6	1A, 2A, 3A	Data Inputs
7, 5, 2	1Y, 2Y, 3Y	Data Outputs
4	GND	Ground (0V)
8	V_{CC}	Positive Supply Voltage

TRUTH TABLE

A	Y
L	H
H	L

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7.0	V
V_I	DC Input Voltage	-0.5 to +7.0	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	- 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	4.5 to 5.5	V
V_I	Input Voltage	0 to 5.5	V
V_O	Output Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature	-55 to 125	°C
dt/dv	Input Rise and Fall Time (note 1) (V_{CC} = 5.0 ± 0.5V)	0 to 20	ns/V

1) V_{IN} from 0.8V to 2V

DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value							Unit
		V_{CC} (V)		T_A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	4.5 to 5.5		2			2		2		V
V_{IL}	Low Level Input Voltage	4.5 to 5.5				0.8		0.8		0.8	V
V_{OH}	High Level Output Voltage	4.5	I_O=-50 µA	4.4	4.5		4.4		4.4		V
		4.5	I_O=-8 mA	3.94			3.8		3.7		
V_{OL}	Low Level Output Voltage	4.5	I_O=50 µA		0.0	0.1		0.1		0.1	V
		4.5	I_O=8 mA			0.36		0.44		0.55	
I_I	Input Leakage Current	0 to 5.5	V_I = 5.5V or GND			± 0.1		± 1.0		± 1.0	µA
I_{CC}	Quiescent Supply Current	5.5	V_I = V_{CC} or GND			1		10		20	µA
$\triangle I_{CC}$	Additional Worst Case Supply Current	5.5	One Input at 3.4V, other input at V_{CC} or GND			1.35		1.5		1.5	mA

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3ns)

Symbol	Parameter	Test Condition			Value						Unit
		V_{CC} (V)	C_L (pF)		T_A = 25°C			-40 to 85°C		-55 to 125°C	
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{PLH}	Propagation Delay Time	5.0 (*)	15			4.7	6.7	1.0	7.5	1.0	8.5	ns
t_{PHL}		5.0 (*)	50			5.5	7.7	1.0	8.5	1.0	9.5	

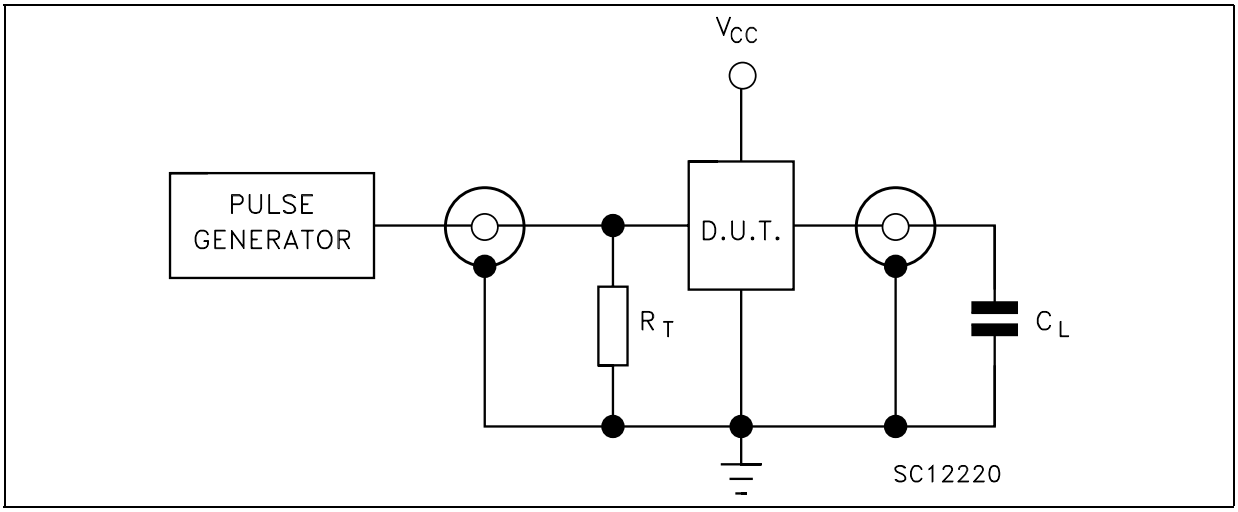
(*) Voltage range is 5.0V ± 0.5V

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition	Value							Unit
			T_A = 25°C			-40 to 85°C		-55 to 125°C		
			Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
C_{IN}	Input Capacitance			4	10		10		10	pF
C_{PD}	Power Dissipation Capacitance (note 1)			16						pF

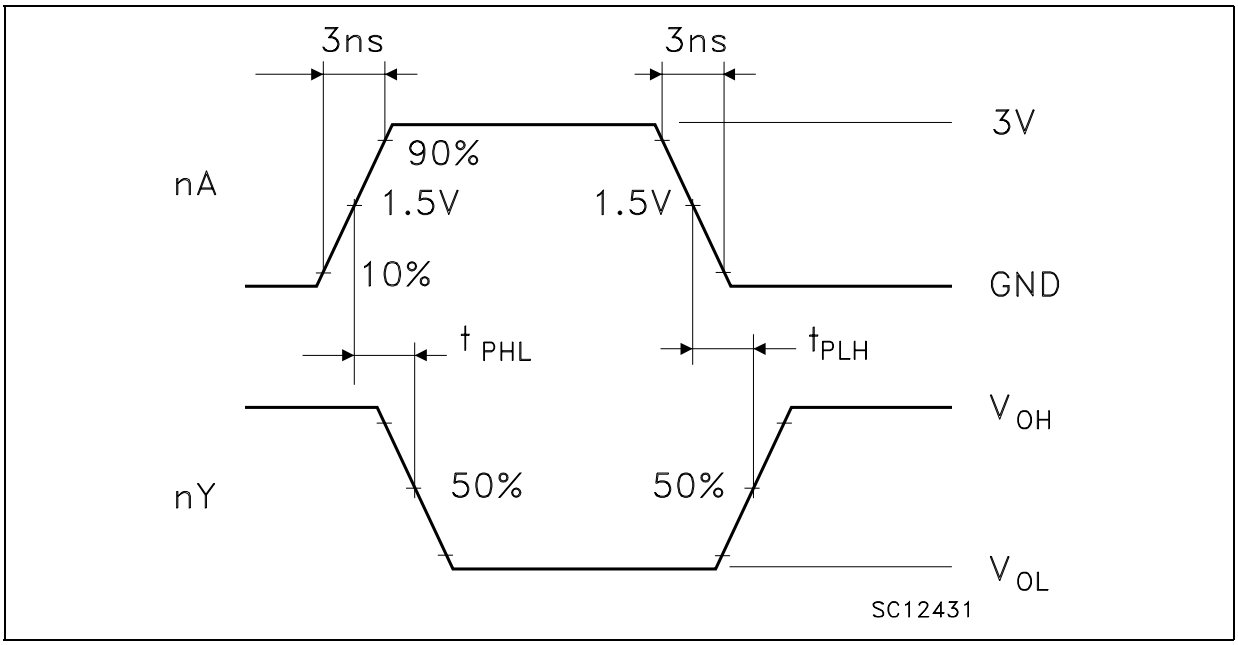
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/3$

TEST CIRCUIT



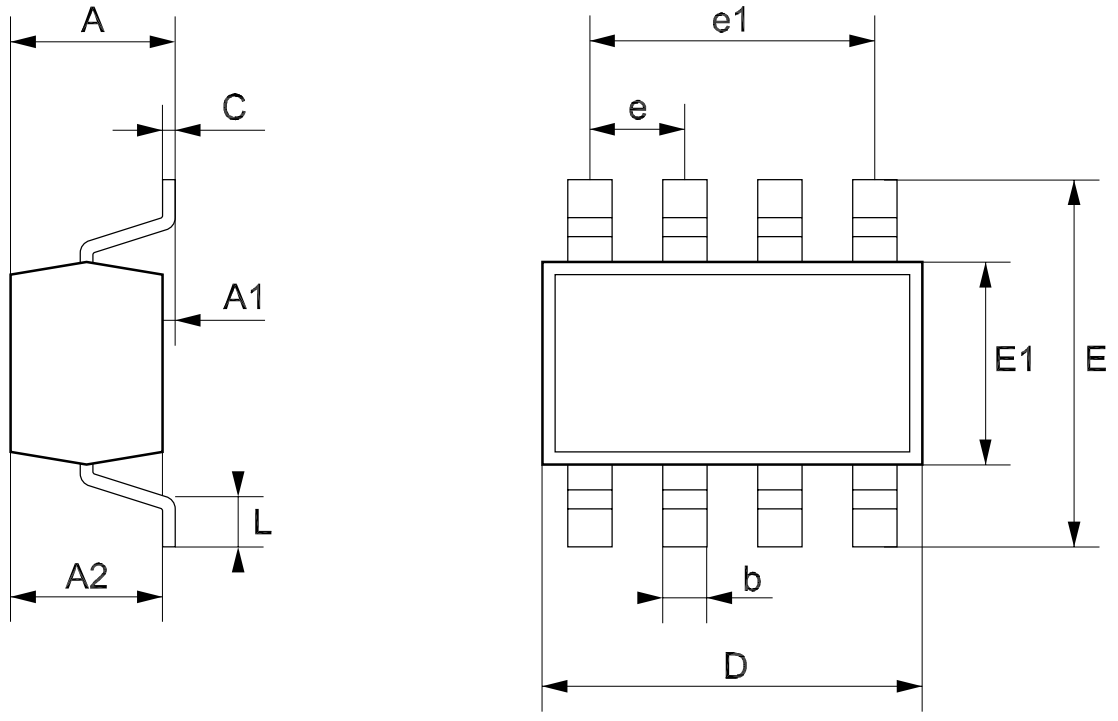
C_L =15/50pF or equivalent (includes jig and probe capacitance)
$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAY (f=1MHz; 50% duty cycle)



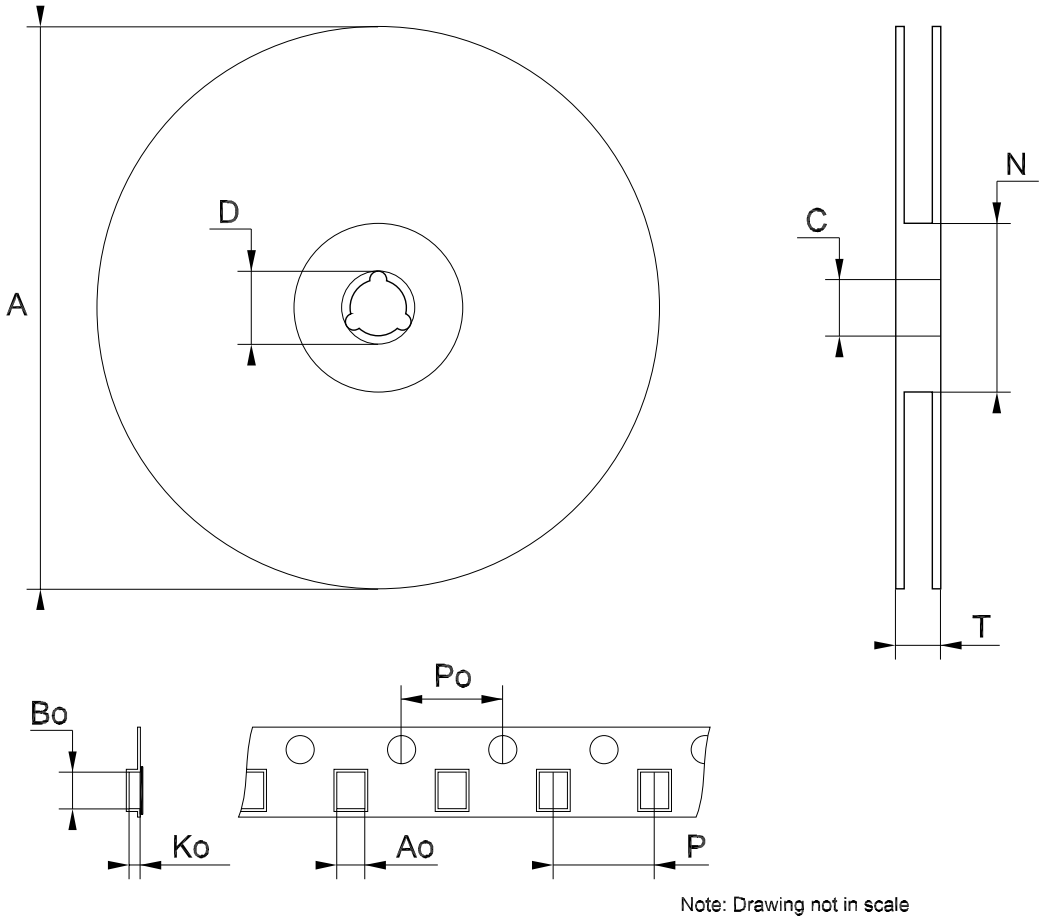
SOT23-8L MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.0		5.9
A2	0.90		1.30	35.4		51.2
b	0.22		0.38	8.6		14.9
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
e	0	.65			25.6	
e1		1.95			76.7	
L	0.35		0.55	13.7		21.6



Tape & Reel SOT23-xL MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			180			7.086
C	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
T			14.4			0.567
Ao	3.13	3.23	3.33	0.123	0.127	0.131
Bo	3.07	3.17	3.27	0.120	0.124	0.128
Ko	1.27	1.37	1.47	0.050	0.054	0.0.58
Po	3.9	4.0	4.1	0.153	0.157	0.161
P	3.9	4.0	4.1	0.153	0.157	0.161



Note: Drawing not in scale

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